

DESCRIPTION

The 1SS226 is available in SOT-23 package

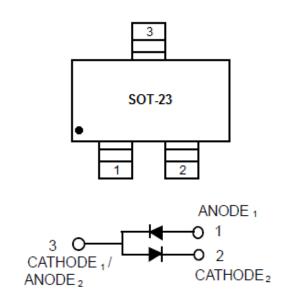
FEATURES

- Low forward voltage : $V_{F(3)} = 0.9V(typ.)$
- Fast reverse recovery time : t_{RR}=1.6ns(typ.)
- Small total capacitance : C_T=0.9pF(typ.)
- Available in SOT-23 package

ORDERING INFORMATION

Package Type	Part Number			
SOT-23	1SS226			
Note	SPQ: 3,000pcs/Reel			
AiT provides all RoHS Compliant Products				

PIN DESCRIPTION



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ABSOLUTE MAXIMUM RATINGS

V _{RM} , Maximum (Peak) Reverse Voltage	85V
V _R , Reverse Voltage	80V
I _{FM} , Maximum (Peak) Forward Current	300mA ^{NOTE1}
Io, Average Forward Current	100mA NOTE1
I _{FSM} , Surge Current (10ms)	2A NOTE1
P, Power Dissipation	150mW
T _J , Junction Temperature	125°C
T _{STG} , Storage Temperature Range	-55°C~125°C

Stresses above may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated in the Electrical Characteristics are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

NOTE1: Unit rating. Total rating = Unit rating \times 0.7.

ELECTRICAL CHARACTERISTICS

 $T_A = 25^{\circ}C$

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Forward Voltage	V _{F(1)}	I _F =1mA		0.60		V
	V _{F(2)}	I _F =10mA		0.72		
	V _{F(3)}	I _F =100mA		0.90	1.20	
Reverse Current	I _{R(1)}	V _R =30V			0.1	μΑ
	I _{R(2)}	V _R =80V			0.5	
Total Capacitance	Ст	V _R =0, f=1MHz		0.9	3.0	pF
Reverse Recovery Time	t _{rr}	I _F =10mA (Fig.1)		1.6	4.0	ns

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TYPICAL CHARACTERISTICS

Figure 1.Forward Voltage V_{F(V)}

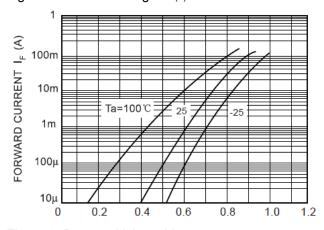


Figure 3. Reverse Voltage V_{R(V)}

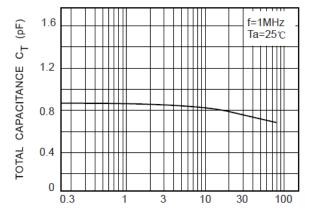


Figure 5. Reverse Recovery Time (t_{rr}) Test Circuit

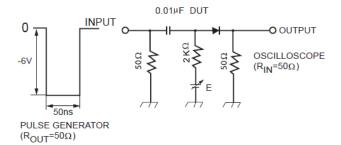


Figure 2. Reverse Voltage V_{R(V)}

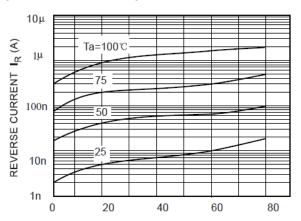
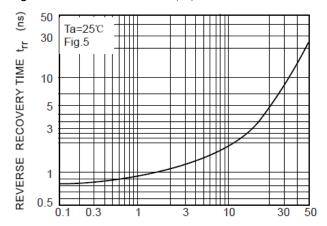
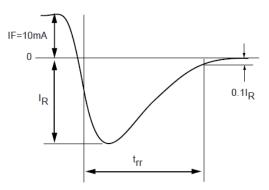


Figure 4. Forward Current I_{F(mA)}



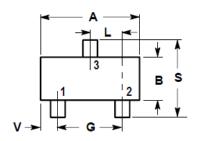
OUTPUT WAVEFORM

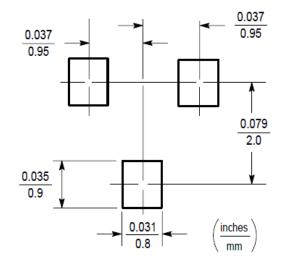


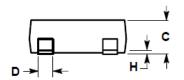
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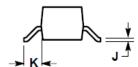
PACKAGE INFORMATION

Dimension in SOT-23 Package (Unit: mm)









DIM	MILLIMETERS		INCHES		
	MIN	MAX	MIN	MAX	
А	2.800	3.040	0.1102	0.1197	
В	1.200	1.400	0.0472	0.0551	
С	0.890	1.110	0.0350	0.0440	
D	0.370	0.500	0.0150	0.0200	
G	1.780	2.040	0.0701	0.0807	
Н	0.013	0.100	0.0005	0.0040	
J	0.085	0.177	0.0034	0.0070	
К	0.350	0.690	0.0140	0.0285	
L	0.890	1.020	0.0350	0.0401	
S	2.100	2.640	0.0830	0.1039	
V	0.450	0.600	0.0177	0.0236	

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